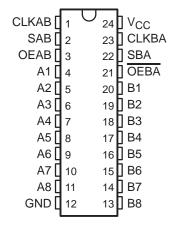
- State-of-the-Art *EPIC-IIB™* BiCMOS Design **Significantly Reduces Power Dissipation**
- **ESD Protection Exceeds 2000 V Per** MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- Latch-Up Performance Exceeds 500 mA Per **JEDEC Standard JESD-17**
- Typical V_{OLP} (Output Ground Bounce) < 1 V at V_{CC} = 5 V, T_A = 25°C
- High-Drive Outputs (-32-mA I_{OH}, 64-mA I_{OL})
- **Package Options Include Plastic** Small-Outline (DW), Shrink Small-Outline (DB), and Thin Shrink Small-Outline (PW) Packages, Ceramic Chip Carriers (FK), Ceramic Flat (W) Package, and Plastic (NT) and Ceramic (JT) DIPs

description

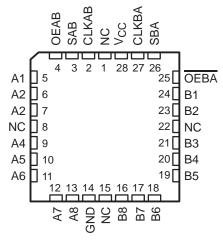
These devices consist of bus-transceiver circuits, D-type flip-flops, and control circuitry arranged for multiplexed transmission of data directly from the data bus or from the internal storage registers.

Output-enable (OEAB and OEBA) inputs are provided to control the transceiver functions. Select-control (SAB and SBA) inputs are provided to select either real-time or stored data for transfer. The circuitry used for select control eliminates the typical decoding glitch that occurs in a multiplexer during the transition between stored and real-time data. A low input selects real-time data, and a high input selects stored data. Figure 1 illustrates the four fundamental bus-management functions that can be performed with the 'ABT652A.

SN54ABT652A . . . JT OR W PACKAGE SN74ABT652A...DB, DW, NT, OR PW PACKAGE (TOP VIEW)



SN54ABT652A . . . FK PACKAGE (TOP VIEW)



NC - No internal connection

Data on the A- or B-data bus, or both, can be stored in the internal D-type flip-flops by low-to-high transitions at the appropriate clock (CLKAB or CLKBA) inputs, regardless of the select- or enable-control inputs. When SAB and SBA are in the real-time transfer mode, it is possible to store data without using the internal D-type flip-flops by simultaneously enabling OEAB and OEBA. In this configuration, each output reinforces its input. When all other data sources to the two sets of bus lines are at high impedance, each set of bus lines remains at its last

To ensure the high-impedance state during power up or power down, $\overline{\text{OEBA}}$ should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver (B to A). OEAB should be tied to GND through a pulldown resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver (A to B).



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

EPIC-IIB is a trademark of Texas Instruments Incorporated



SN54ABT652A, SN74ABT652A OCTAL REGISTERED TRANSCEIVERS WITH 3-STATE OUTPUTS

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description (continued)

The SN54ABT652A is characterized for operation over the full military temperature range of -55° C to 125° C. The SN74ABT652A is characterized for operation from -40° C to 85° C.

FUNCTION TABLE

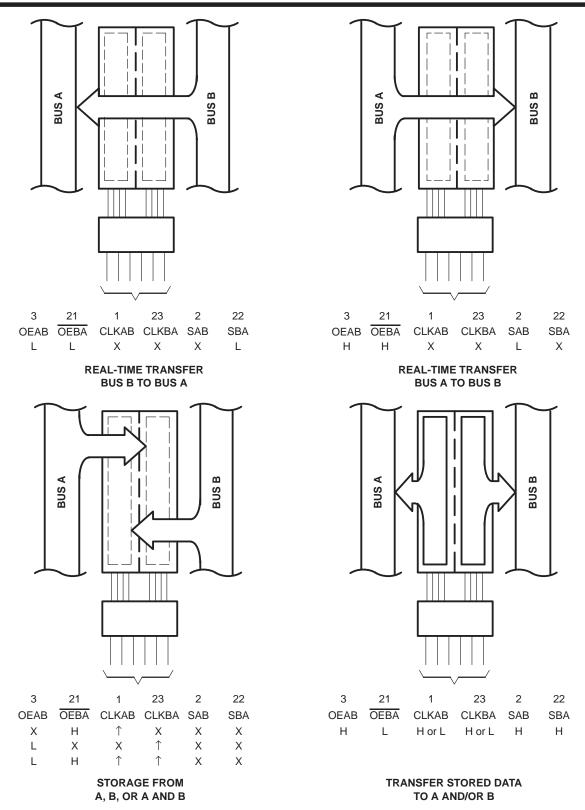
		INP	UTS			DATA	1/0†	ODED ATION OF FUNCTION
OEAB	OEBA	CLKAB	CLKBA	SAB	SBA	A1-A8	B1-B8	OPERATION OR FUNCTION
L	Н	H or L	H or L	Х	Х	Input	Input	Isolation
L	Н	1	↑	Χ	Χ	Input	Input	Store A and B data
Х	Н	1	H or L	Х	Χ	Input	Unspecified [‡]	Store A, hold B
Н	Н	\uparrow	\uparrow	X [‡]	Χ	Input	Output	Store A in both registers
L	Χ	H or L	↑	Х	Χ	Unspecified [‡]	Input	Hold A, store B
L	L	1	1	Χ	X‡	Output	Input	Store B in both registers
L	L	Х	Х	Х	L	Output	Input	Real-time B data to A bus
L	L	Χ	H or L	X	Н	Output	Input	Stored B data to A bus
Н	Н	Х	Х	L	Х	Input	Output	Real-time A data to B bus
Н	Н	H or L	Χ	Н	Χ	Input	Output	Stored A data to B bus
Н	L	H or L	H or L	Н	Н	Output	Output	Stored A data to B bus and stored B data to A bus

[†] The data-output functions may be enabled or disabled by a variety of level combinations at OEAB or OEBA. Data-input functions are always enabled; i.e., data at the bus terminals is stored on every low-to-high transition of the clock inputs.



[‡] Select control = L; clocks can occur simultaneously.

Select control = H; clocks must be staggered to load both registers.



Pin numbers shown are for the DB, DW, JT, NT, PW, and W packages.

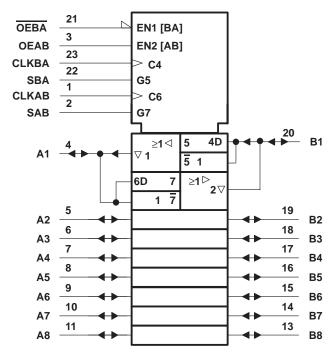
Figure 1. Bus-Management Functions



SN54ABT652A, SN74ABT652A OCTAL REGISTERED TRANSCEIVERS WITH 3-STATE OUTPUTS

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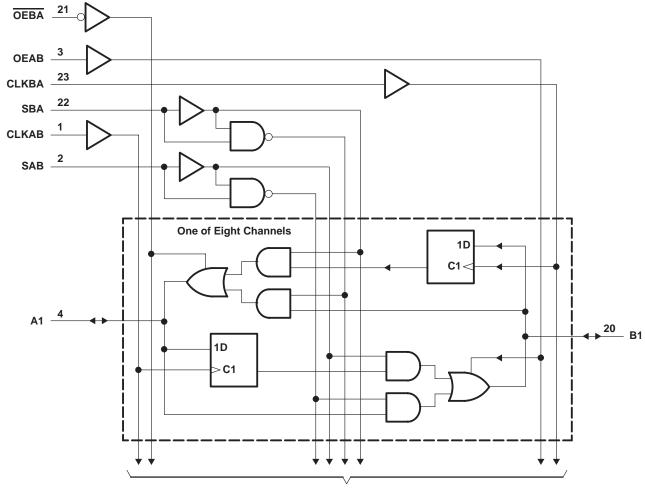
logic symbol†



 $^{^\}dagger$ This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12. Pin numbers shown are for the DB, DW, JT, NT, PW, and W packages.



logic diagram (positive logic)



To Seven Other Channels

Pin numbers shown are for the DB, DW, JT, NT, PW, and W packages.

SN54ABT652A, SN74ABT652A OCTAL REGISTERED TRANSCEIVERS WITH 3-STATE OUTPUTS

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}		0.5 V to 7 V
Input voltage range, V _I (except I/O ports) (see Note		
Voltage range applied to any output in the high or pe	ower-off state, VO	-0.5 V to 5.5 V
Current into any output in the low state, Io: SN54A	BT652A	96 mA
SN74A	BT652A	128 mA
Input clamp current, I _{IK} (V _I < 0)		–18 mA
Output clamp current, I_{OK} ($V_O < 0$)		–50 mA
Package thermal impedance, θ _{JA} (see Note 2): DB	package	104°C/W
DW	/ package	81°C/W
NT	package	67°C/W
PW	/ package	120°C/W
Storage temperature range, T _{stq}		-65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

2. The package thermal impedance is calculated in accordance with EIA/JEDEC Std JESD51, except for through-hole packages, which use a trace length of zero.

recommended operating conditions (see Note 3)

			SN54AB	T652A	SN74AB	T652A	UNIT
			MIN	MAX	MIN	MAX	UNIT
VCC	Supply voltage		4.5	5.5	4.5	5.5	V
VIH	High-level input voltage		2		2		V
VIL	Low-level input voltage			0.8		0.8	V
VI	Input voltage		0	VCC	0	VCC	V
IOH	High-level output current			-24		-32	mA
loL	Low-level output current			48		64	mA
Δt/Δν	Input transition rise or fall rate	Outputs enabled		5		5	ns/V
TA	Operating free-air temperature		- 55	125	-40	85	°C

NOTE 3: Unused pins (input or I/O) must be held high or low to prevent them from floating.



electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CO	NOITIONS	Т	A = 25°C	;	SN54AB	T652A	SN74AB	T652A	UNIT
PARAMETER	1231 00	NDITIONS	MIN	TYP [†]	MAX	MIN	MAX	MIN	MAX	UNII
VIK	$V_{CC} = 4.5 \text{ V},$	$I_{I} = -18 \text{ mA}$			-1.2		-1.2		-1.2	V
	$V_{CC} = 4.5 \text{ V},$	$I_{OH} = -3 \text{ mA}$	2.5			2.5		2.5		
\/a	$V_{CC} = 5 V$	$I_{OH} = -3 \text{ mA}$	3			3		3		V
VOH	V _{CC} = 4.5 V	$I_{OH} = -24 \text{ mA}$	2			2				V
	VCC = 4.5 V	$I_{OH} = -32 \text{ mA}$	2*					2		
Vol	V _{CC} = 4.5 V	$I_{OL} = 48 \text{ mA}$			0.55		0.55			V
VOL	VCC = 4.5 V	I _{OL} = 64 mA			0.55*				0.55	V
V _{hys}				100						mV
Control inpu	v _{CC} = 5.5 V,	V _I = V _{CC} or GND			±1		±1		±1	μΑ
A or B ports	VCC = 5.5 V,	vi = vCC or GND			±100		±100		±100	μΑ
^I OZH [‡]	$V_{CC} = 5.5 V$,	V _O = 2.7 V			50**		10		50	μΑ
lozL [‡]	$V_{CC} = 5.5 \text{ V},$	V _O = 0.5 V			-50**		-10		-50	μΑ
loff	$V_{CC} = 0$,	V_I or $V_O \le 4.5 \text{ V}$			±100				±100	μΑ
ICEX	V _{CC} = 5.5 V, V _O = 5.5 V	Outputs high			50		50		50	μΑ
ΙΟ [§]	V _{CC} = 5.5 V,	V _O = 2.5 V	-50	-100	-180	-50	-180	-50	-180	mA
	V _{CC} = 5.5 V,	Outputs high			250		250		250	μΑ
ICC	$I_{O} = 0$,	Outputs low			30		30		30	mA
	$V_I = V_{CC}$ or GND	Outputs disabled			250		250		250	μΑ
ΔI _{CC} ¶	ΔI_{CC} V _{CC} = 5.5 V, One in Other inputs at V _{CC}				1.5		1.5		1.5	mA
C _i Control inpu	ts $V_1 = 2.5 \text{ V or } 0.5 \text{ V}$			7						pF
C _{io} A or B ports	V _O = 2.5 V or 0.5 V	'		12						pF

^{*} On products compliant to MIL-PRF-38535, this parameter does not apply.



^{**} These limits apply only to the SN74ABT652A.

[†] All typical values are at $V_{CC} = 5 \text{ V}$.

[‡]The parameters I_{OZH} and I_{OZL} include the input leakage current.

[§] Not more than one output should be tested at a time, and the duration of the test should not exceed one second.

[¶] This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND.

SN54ABT652A, SN74ABT652A OCTAL REGISTERED TRANSCEIVERS WITH 3-STATE OUTPUTS

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timing requirements over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 2)

			SN54AE	3T652A		
		V _{CC} = T _A = 2	= 5 V, 25°C	MIN	MAX	UNIT
		MIN	MAX			
fclock	Clock frequency	0	125	0	125	MHz
t _W	Pulse duration, CLK high or low	4		4		ns
t _{su}	Setup time, A or B before CLKAB↑ or CLKBA↑	3		3.5		ns
th	Hold time, A or B after CLKAB↑ or CLKBA↑	1.5		1.5		ns

timing requirements over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 2)

			SN74ABT652A				
		V _{CC} =	= 5 V, 25°C	MIN	MAX	UNIT	
		MIN	MAX				
fclock	Clock frequency	0	125	0	125	MHz	
t _W	Pulse duration, CLK high or low	4		4		ns	
t _{su}	Setup time, A or B before CLKAB↑ or CLKBA↑	3		3		ns	
th	Hold time, A or B after CLKAB↑ or CLKBA↑	0		0		ns	



switching characteristics over recommended ranges of supply voltage and operating free-air temperature, C_L = 50 pF (unless otherwise noted) (see Figure 2)

				SN5	4ABT65	52A		
PARAMETER	FROM (INPUT)	TO (OUTPUT)		CC = 5 V 4 = 25°C		MIN	MAX	UNIT
				TYP	MAX			
fmax			125	200		125		MHz
^t PLH	CLK	B or A	2.2	4	5.1	1.7	5.9	ns
t _{PHL}	OLK	BULK	1.7	4	5.1	1.7	5.9	115
t _{PLH}	A or B	B or A	1.5	3	4.8	1	5	ns
t _{PHL}	AUID	BULA	1.5	3.3	4.6	1	5.6	115
t _{PLH}	048 084	B or A	1.5	4	5.5	1.5	6.8	ns
t _{PHL}	SAB or SBA†	BUIA	1.5	3.6	4.9	1.5	6.2	110
^t PZH	OEBA	А	2	3.6	5.4	2	6.8	ns
t _{PZL}	OEBA	Α	3	5.7	7.7	3	9.2	115
t _{PHZ}	OFDA.	А	1.5	3.2	5.8	1	7.5	ns
t _{PLZ}	OEBA	A	1.5	3	4.3	1	4.6	115
^t PZH	OEAB	В	2	4.3	6.1	2	7.8	
t _{PZL}	OEAB	Ь	3	5.5	7.4	3	8.9	ns
t _{PHZ}	OEAB	В	1.5	3.3	6	1	8	no
t _{PLZ}	OLAB	٥	1.5	3.4	5	1.5	6.8	ns l

[†] These parameters are measured with the internal output state of the storage register opposite that of the bus input.

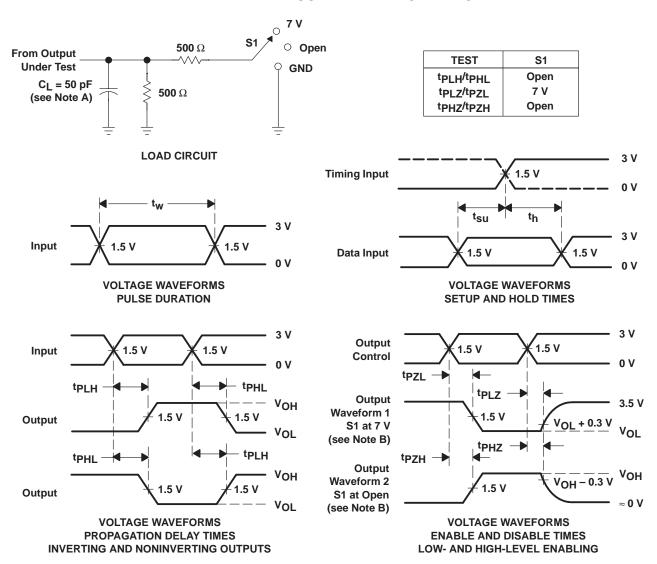
switching characteristics over recommended ranges of supply voltage and operating free-air temperature, C_L = 50 pF (unless otherwise noted) (see Figure 2)

				SN7	4ABT65	52A		
PARAMETER	FROM (INPUT)	TO (OUTPUT)		CC = 5 V 4 = 25°C		MIN	MAX	UNIT
			MIN	TYP	MAX			
f _{max}			125	200		125		MHz
^t PLH	CLK	B or A	2.2	4	5.1	2.2	5.6	ns
t _{PHL}	CLN	BOIA	1.7	4	5.1	1.7	5.6	115
^t PLH	A or B	B or A	1.5	3	4.3	1.5	4.8	ns
t _{PHL}	AOIB	BOIA	1.5	3.3	4.6	1.5	5.4	113
^t PLH	SAB or SBA†	B or A	1.5	4	5.1	1.5	6.5	ns
t _{PHL}	SAB OF SBAT	BOIA	1.5	3.6	4.9	1.5	5.9	115
^t PZH	 OEBA	А	2	3.6	4.6	2	5.8	ns
t _{PZL}	OEBA	^	3	5.7	6.8	3	8.5	115
^t PHZ	OEBA	А	1.5	3.2	4.5	1.5	5	ns
t _{PLZ}	OEBA	^	1.5	3	3.8	1.5	4.1	115
^t PZH	OEAB	В	2	4.3	6.1	2	6.5	
t _{PZL}	OLAB		3	5.5	6.5	3	7.4	ns
t _{PHZ}	OEAB	В	1.5	3.3	4.5	1.5	5.5	ns
^t PLZ] OLAB		1.5	3.4	4.4	1.5	5.1	115

[†] These parameters are measured with the internal output state of the storage register opposite that of the bus input.



PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_{O} = 50 \Omega$, $t_{f} \leq 2.5 \text{ ns.}$
- D. The outputs are measured one at a time with one transition per measurement.

Figure 2. Load Circuit and Voltage Waveforms







25-Oct-2016

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
5962-9324202Q3A	ACTIVE	LCCC	FK	28	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 9324202Q3A SNJ54ABT 652AFK	Samples
5962-9324202QKA	ACTIVE	CFP	W	24	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9324202QK A SNJ54ABT652AW	Samples
5962-9324202QLA	ACTIVE	CDIP	JT	24	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9324202QL A SNJ54ABT652AJT	Samples
SN74ABT652ADBLE	OBSOLETI	SSOP	DB	24		TBD	Call TI	Call TI	-40 to 85		
SN74ABT652ADBR	ACTIVE	SSOP	DB	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	AB652A	Samples
SN74ABT652ADBRE4	ACTIVE	SSOP	DB	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	AB652A	Samples
SN74ABT652ADW	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ABT652A	Samples
SN74ABT652ADWR	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ABT652A	Samples
SNJ54ABT652AFK	ACTIVE	LCCC	FK	28	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 9324202Q3A SNJ54ABT 652AFK	Samples
SNJ54ABT652AJT	ACTIVE	CDIP	JT	24	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9324202QL A SNJ54ABT652AJT	Samples
SNJ54ABT652AW	ACTIVE	CFP	W	24	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9324202QK A SNJ54ABT652AW	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

PACKAGE OPTION ADDENDUM



25-Oct-2016

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF SN54ABT652A, SN74ABT652A:

Catalog: SN74ABT652A

Military: SN54ABT652A

NOTE: Qualified Version Definitions:

Catalog - TI's standard catalog product



PACKAGE OPTION ADDENDUM

25-Oct-2016

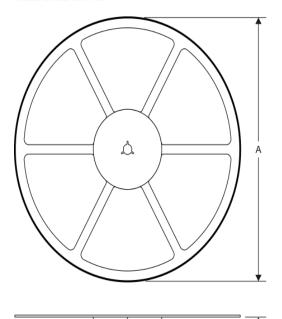
• Military - QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

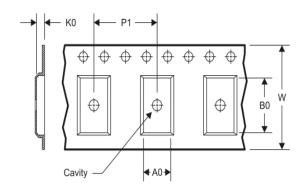
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TAPE AND REEL INFORMATION

REEL DIMENSIONS



TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

TAPE AND REEL INFORMATION

*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74ABT652ADBR	SSOP	DB	24	2000	330.0	16.4	8.2	8.8	2.5	12.0	16.0	Q1
SN74ABT652ADWR	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1

PACKAGE MATERIALS INFORMATION

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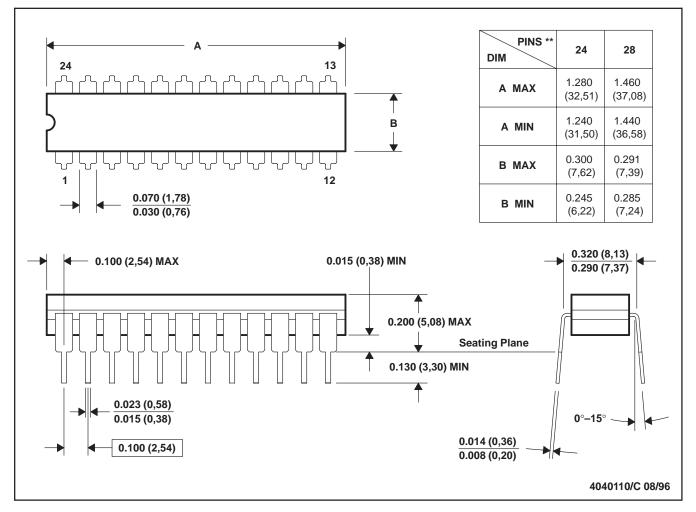
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74ABT652ADBR	SSOP	DB	24	2000	367.0	367.0	38.0
SN74ABT652ADWR	SOIC	DW	24	2000	367.0	367.0	45.0

JT (R-GDIP-T**)

24 LEADS SHOWN

CERAMIC DUAL-IN-LINE



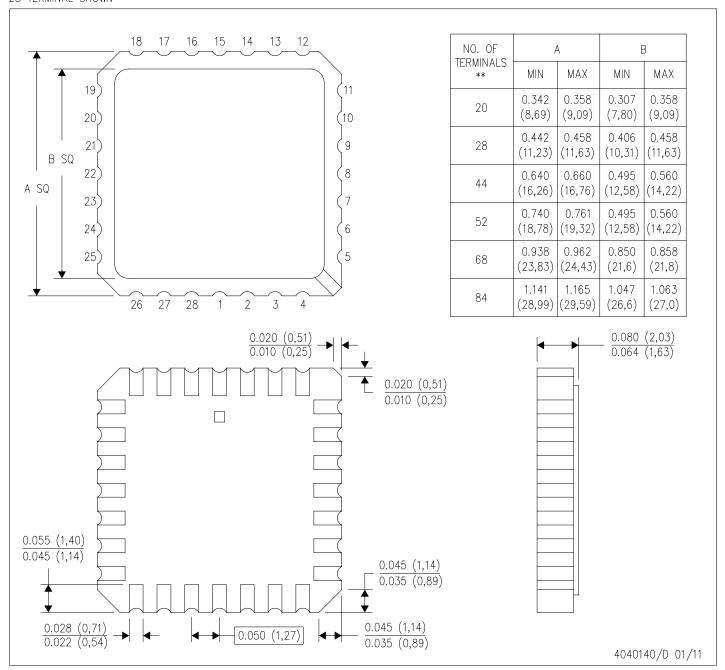
NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification.
- E. Falls within MIL STD 1835 GDIP3-T24, GDIP4-T28, and JEDEC MO-058 AA, MO-058 AB

FK (S-CQCC-N**)

LEADLESS CERAMIC CHIP CARRIER

28 TERMINAL SHOWN



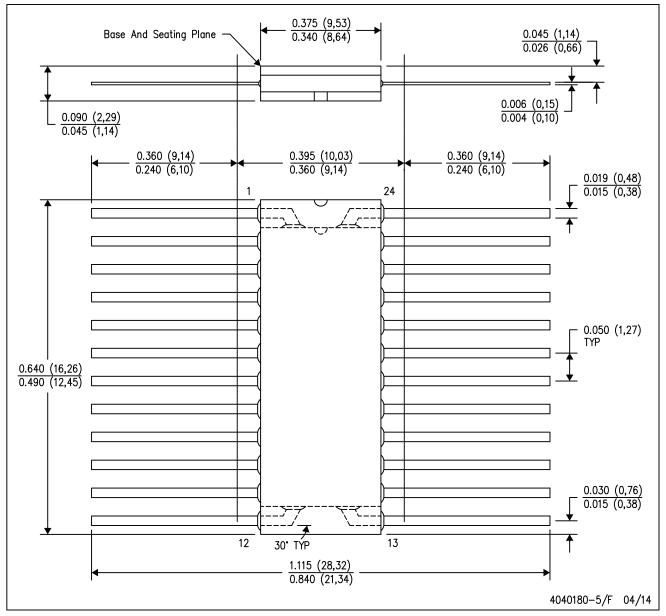
NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a metal lid.
- D. Falls within JEDEC MS-004



W (R-GDFP-F24)

CERAMIC DUAL FLATPACK



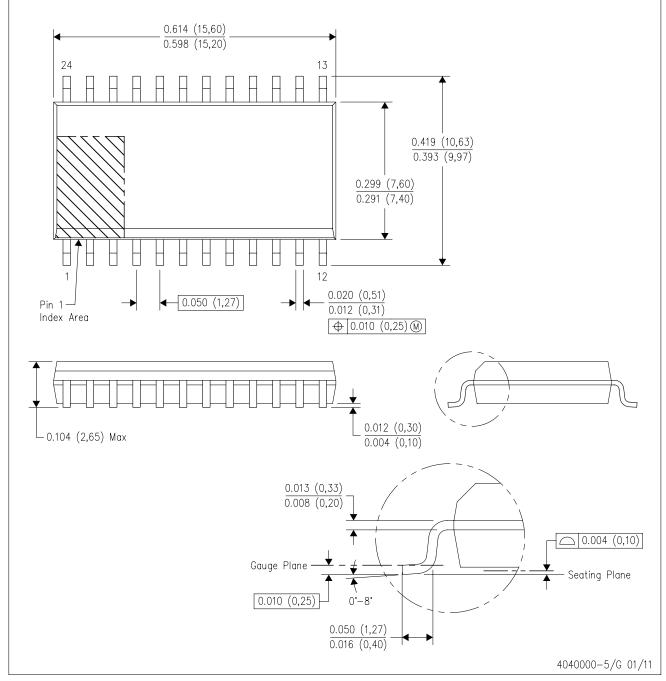
NOTES:

- A. All linear dimensions are in inches (millimeters).
- This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only. E. Falls within Mil—Std 1835 GDFP2—F20



DW (R-PDSO-G24)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.

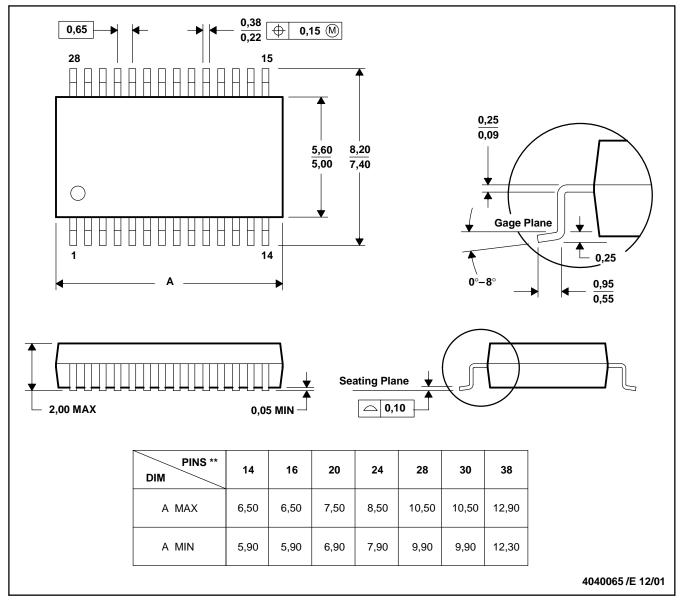
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AD.



DB (R-PDSO-G**)

PLASTIC SMALL-OUTLINE

28 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-150

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